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(54) **METHOD FOR SEPARATING SURFACE LAYER OR GROWTH LAYER OF DIAMOND**

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(58) **Field of Classification Search**

None  
See application file for complete search history.

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(57) **ABSTRACT**

The present invention provides a method for separating a surface layer of a diamond, which comprises implanting ions into a diamond to form a non-diamond layer near a surface of the diamond; and etching the non-diamond layer in the diamond by applying an alternating-current voltage across electrodes in an electrolytic solution; and a method for separating a grown layer of a diamond, which further comprises the step of growing a diamond by a vapor-phase synthesis method, after forming a non-diamond layer according to the above-described method. The invention is applicable to various single-crystal and polycrystal diamonds. More specifically, even with a large single-crystal diamond, a portion of the single-crystal diamond can be efficiently separated in a reusable form in a relatively short period of time.

**10 Claims, 1 Drawing Sheet**

